Low-Power Audio Amplifier for Telephone Applications

Description

The integrated circuit, U4083B, is a low power audio amplifier for a telephone loudspeaker. It has differential speaker outputs to maximize the output swing at low supply voltages. There is no need for coupler capacitors. The U4083B has an open loop gain of 80 dB whereas the closed loop gain is adjusted with two external resistors. A chip disable pin permits powering down and/or muting the input signal.

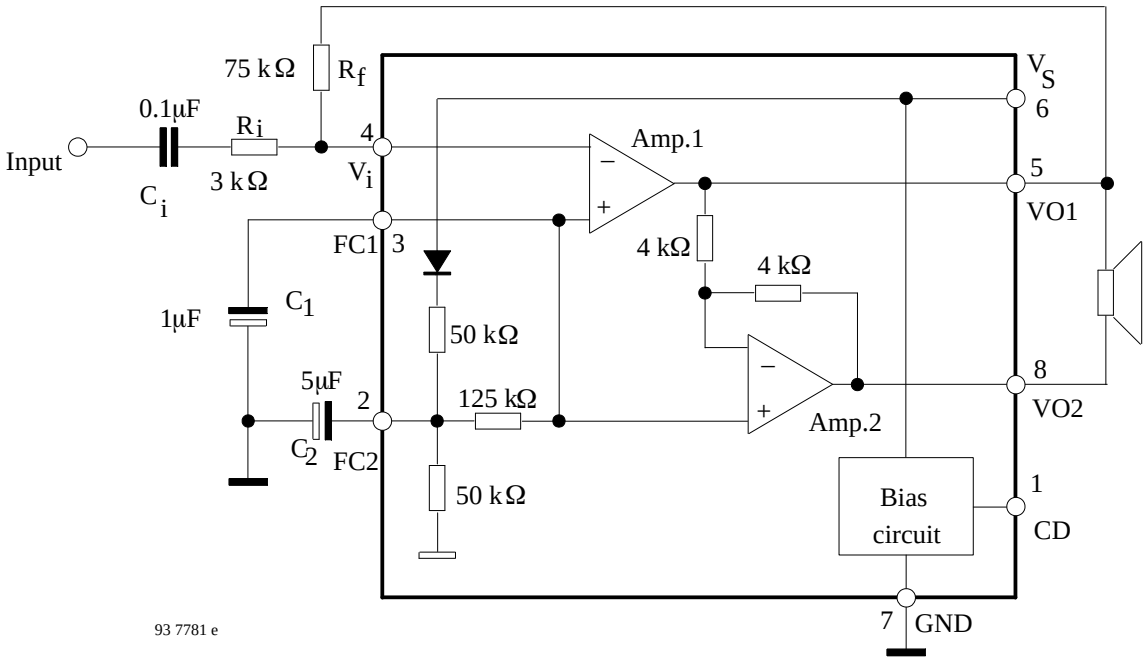
Features

- Wide operating voltage range: 2 to 16 V
- Battery powered application due to low quiescent supply current: 2.7 mA typical
- Chip disable input to power down the integrated circuit
- Low power down quiescent current
- Drives a wide range of speaker loads
- Output Power, P_o = 250 mW @ R_L = 32 Ω (speaker)
- Low harmonic distortion (0.5% typical)
- Wide range gain adjustable: 0 dB to 46 dB

Benefits

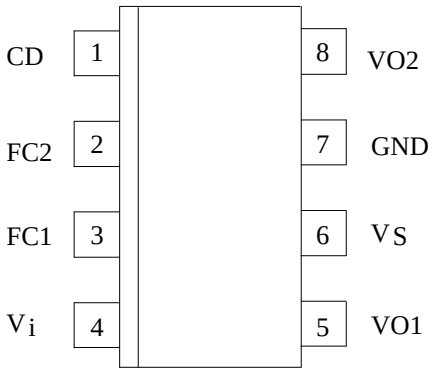
- Low number of external components
- Low current consumption

Block Diagram / Application Circuit



Pin Description

Pin	Symbol	Function
1	CD	Chip disable
2	FC2	Filtering, power supply rejection
3	FC1	Filtering, power supply rejection
4	V_i	Amplifier input
5	VO1	Amplifier output 1
6	V_S	Voltage supply
7	GND	Ground
8	VO2	Amplifier output 2



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Pin Connections and Functional Description Including External Circuitry

Pin 1: Chip disable – digital input (CD)

Pin 1 (chip disable) is used to power down the IC to conserve power or muting or both.

Input impedance at pin 1 is typically 90 kΩ.

Logic 0 < 0.8 V	IC enabled (normal operation)
Logic 1 > 2 V	IC disabled

Figure 15 shows power supply current diagram. The change in differential gain from normal operation to muted operation (muting) is more than 70 dB.

Switching characteristics are as follows:

turn-on time	t_{on} = 12 to 15 ms
turn-off time	$t_{off} \leq 2$ µs

They are independent of C_1, C_2 and V_S.

Voltages at Pins 2 and 3 are supplied from V_S and therefore do not change when the U4083B is disabled. Outputs– V_{O1} (Pin 5) and V_{O2} (Pin 8) –turn to a high impedance condition by removing the signal from the speaker.

When signals are applied from an external source to the outputs (disabled), they must not exceed the range between the supply voltage, V_s, and Ground.

Pins 2 and 3: Filtering, power supply rejection

Power supply rejection is provided by capacitors C_1 and C_2 at Pin 3 and Pin 2, respectively. C_1 is dominant at high frequencies whereas C_2 is dominant at low frequencies (figures 4 to 7). Values of C_1 and C_2 depend on the conditions of each application. For example, a line powered speakerphone (telephone amplifier) will require more filtering than a system powered by regulated power supply.

The amount of rejection is a function of the capacitors and the equivalent impedance looking into Pin 3 and Pin 2 (see electrical characteristic equivalent resistance, R).

Apart from filtering, capacitors C_1 and C_2 also influence the turn-on time of the circuit at power-up since capacitors are charged up through the internal resistors (50 kΩ and 125 kΩ) as shown in the block diagram.

Figure 1 shows turn-on time versus C_2 at V_S = 6 V, for two different C_1 values.

Turn-on time is 60% longer when V_S = 3 V and 20% shorter when V_S = 9 V.

Turn-off time is less than 10 µs

Pin 4: Amplifier input **V_i**

Pin 5: Amplifier output 1 **V_{O1}**

Pin 8: Amplifier output 2 **V_{O2}**

There are two identical operational amplifiers. Amp.1 has an open loop gain ≥ 80 dB at 100 Hz (figure 2), whereas the closed loop gain is set by external resistors, Rf and Ri (figure 3). The amplifier is unity gain stable, and has a unity gain frequency of approximately 1.5 MHz. A closed loop gain of 46 dB is recommended for a frequency range of 300 to 3400 Hz (voice band). Amp.2 is internally set to a gain of –1.0 (0 dB). The outputs of both amplifiers are capable of sourcing and sinking a peak current of 200 mA. Output voltage swing is between 0.4 V and V_s – 1.3 V at maximum current (figures 18 and 19).

The output dc offset voltage between Pins 5 and 8 (V_{O1} – V_{O2}) is mainly a function of the feedback resistor, R_f, because the input offset voltage of the two amplifiers generally neutralize each other.

Bias current of Amp. 1 which is constant with respect to V_s, however flows out of Pin 4 (V_i) and through R_f, forcing V_{01} to shift negative by an amount equal to R_f I_{IB} and V_{O2} positive to an equal amount.

The output offset voltage specified in the electrical characteristics is measured with the feedback resistor

(R_f = 75 kΩ) shown in typical application circuit. It takes into account bias current as well as internal offset voltages of the amplifiers.

Pin 6: Supply and power dissipation

Power dissipation is shown in figures 8 to 10 for different loads. Distortion characteristics are given in figures 11 to 13.

$$P_{totmax} = \frac{T_{jmax} - T_{amb}}{R_{thJA}}$$

where

T_{jmax} = Junction temperature = 140°C
T_{amb} = Ambient temperature
R_{thJA} = Thermal resistance, junction-ambient

Power dissipated within the IC in a given application is found from the following equation:

$P_{tot} = (V_S \cdot I_S) + (I_{RMS} \cdot V_S) - (R_L \cdot I_{RMS}^2)$

I_S is obtained from figures 15
I_{RMS} is the RMS current at the load R_L.

Operating range of the integrated circuit is defined with a peak operating load current of ± 200 mA (figures 8 to 13). It is further specified with respect to different loads in figure 14. The left (ascending) portion of each of the three curves is defined by the power level at which 10% distortion occurs. The center flat portion of each curve is defined by the maximum output current capability of the integrated circuit. The right (descending) portion of each curve is defined by the maximum internal power dissipation of the IC at 25°C. At higher ambient temperatures, the maximum load power must be reduced according to the above mentioned equation.

Layout Considerations

Normally a snubber is not needed at the output of the IC, unlike many other audio amplifiers. However, the PC board layout, stray capacitances, and the manner in which the speaker wires are configured, may dictate otherwise. Generally the speaker wires should be twisted tightly, and be not more than a few cm (or inches) in length.

Absolute Maximum Ratings

Reference point Pin 7, T_{amb} = 25°C unless otherwise specified.

Parameters		Symbol	Value	Unit
Supply voltage	Pin 6	V_S	–1.0 to +18	V
Voltages Disabled	Pins 1, 2, 3 and 4 Pins 5 and 8		–1.0 to (VS +1.0) –1.0 to (VS +1.0)	V V
Output current	Pins 5 and 8		± 250	mA
Junction temperature		T_j	+140	°C
Storage temperature range		T_{stg}	–55 to +150	°C
Ambient temperature range		T_{amb}	–20 to +70	°C
Power dissipation: T_{amb} = 60°C	SO 8 DIP8	P_{tot} P_{tot}	440 720	mW mW

Thermal Resistance

Parameters		Symbol	Value	Unit
Junction ambient	SO 8 DIP 8	R_{thJA} R_{thJA}	180 110	K/W K/W

Operation Recommendation

Parameters		Symbol	Value	Unit
Supply voltage	Pin 6	V_S	2 to 16	V
Load impedance	Pins 5 to 8	R_L	8.0 to 100	Ω
Load current		I_L	± 200	mA
Differential gain (5.0 kHz bandwidth)		ΔG	0 to 46	dB
Voltage @ CD Pin 1		V_{CD}	VS	V
Ambient temperature range		T_{amb}	–20 to +70	°C

Electrical Characteristics

T_{amb} = +25°C, reference point Pin 7, unless otherwise specified

Parameters	Test Conditions / Pins	Symbol	Min.	Typ.	Max.	Unit
Amplifiers (AC Characteristics)						
Open gain loop (Amp. 1, f < 100 Hz)		G_{VOL1}	80			dB
Closed gain loop (Amp. 2)	V_S = 6.0 V, f = 1.0 kHz, R_L = 32 Ω	G_{V2}	–0.35	0	+0.35	dB
Gain bandwidth product		G_{BW}		1.5		MHz
Output power	V_S = 3.0 V, R_L = 16 Ω, d < 10% V_S = 6.0 V, R_L = 32 Ω, d < 10% V_S = 12 V, R_L = 100 Ω, d < 10%	Po Po Po	55 250 400			mW
Total harmonic distortion (f = 1.0 kHz)	V_S = 6.0 V, R_L = 32 Ω, P_o = 125 mW V_S > 3.0 V, R_L = 8 Ω, P_o = 20 mW V_S > 12 V, R_L = 32 Ω, P_o = 200 mW	d d d		0.5 0.5 0.6	1.0	%
Power supply rejection ratio	V_S = 6.0 V, ΔV_S = 3.0 V C_1 = ∝, C_2 = 0.01 µF C_1 = 0.1 µF, C_2 = 0, f = 1.0 kHz C_1 = 1.0 µF, C_2 = 5.0 µF, f = 1.0 kHz	PSRR PSRR PSRR	50	 12 52		dB
Muting	V_S = 6.0 V, 1.0 kHz < f < 20 kHz, CD = 2.0 V	G_{MUTE}		>70		dB
Amplifiers (DC Characteristics)						
Output dc level at V_{O1}, V_{O2} R_f = 75 kW	V_S = 3.0 V, R_L = 16 Ω V_S = 6.0 V V_S = 12 V	V_O V_O V_O	1.0	1.15 2.65 5.65	1.25	V
Output high level	I_O = – 75 mA, 2.0 V < V_S < 16 V	V_{OH}		V_S–1		V
Output low level	I_O = 75 mA, 2.0 V < V_S < 16 V	V_{OL}		0.16		V
Output dc offset voltage (V_{O1} – V_{O2})	V_S = 6.0 V, R_f = 75 kΩ, R_L = 32 Ω	ΔV_O	–30	0	+30	mV
Input bias current at V_i	V_S = 6.0 V	$-I_{IB}$		100	200	nA
Equivalent resistance at Pin 3	V_S = 6.0 V	R	100	150	220	kΩ
Equivalent resistance at Pin 2	V_S = 6.0 V	R	18	25	40	kΩ

Parameters	Test Conditions / Pins	Symbol	Min.	Typ.	Max.	Unit
Chip disable Pin 1 Input voltage – low Input voltage – high Input resistance	 $V_S = V_{CD} = 16$ V	 V_{IL} V_{IH} R_{CD}	 2.0 50	 90	 0.8 175	 V V kW
Power supply current	$V_S = 3.0$ V, $R_L = \propto$, CD = 0.8 V $V_S = 16$ V, $R_L = \propto$, CD = 0.8 V $V_S = 3.0$ V, $R_L = \propto$, CD = 2.0 V	I_S I_S I_S		 65	4.0 5.0 100	mA mA µA

Typical Temperature Performance

$T_{amb} = -20$ to +70°C

Function	Typical Change	Units
Input bias current at V_i	± 40	pA/ °C
Total harmonic distortion $V_S = 6.0$ V, $R_L = 32\ \Omega$, $P_o = 125$ mW, f = 1.0 kHz	+ 0.003	%/ °C
Power supply current $V_S = 3.0$ V, $R_L = \propto$, CD = 0 V $V_S = 3.0$ V, $R_L = \propto$, CD = 2.0 V	 – 2.5 – 0.03	 µA/ °C µA/ °C

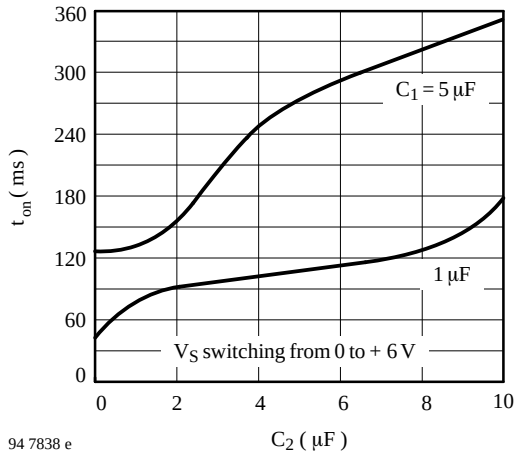


Figure 1.

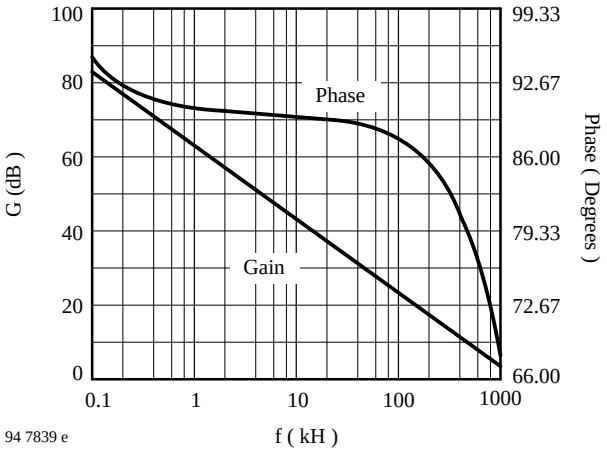
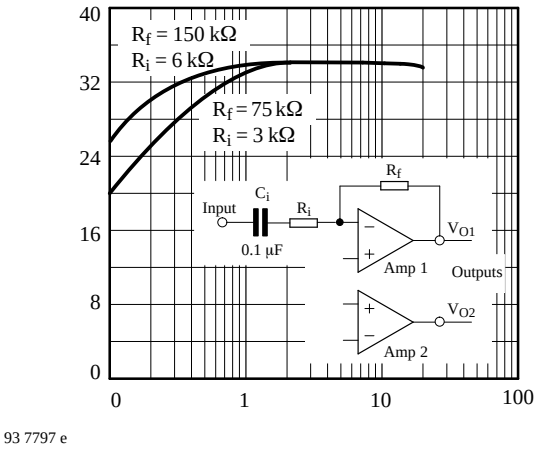


Figure 2.



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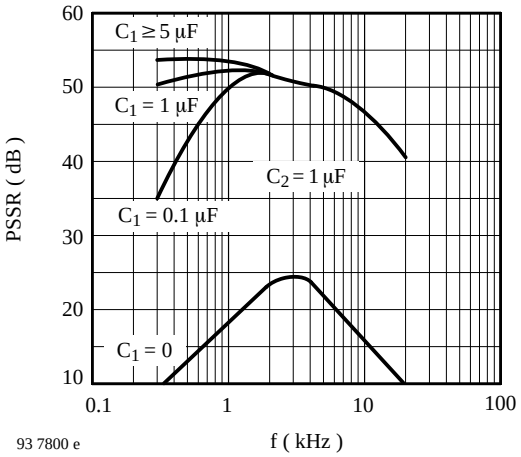

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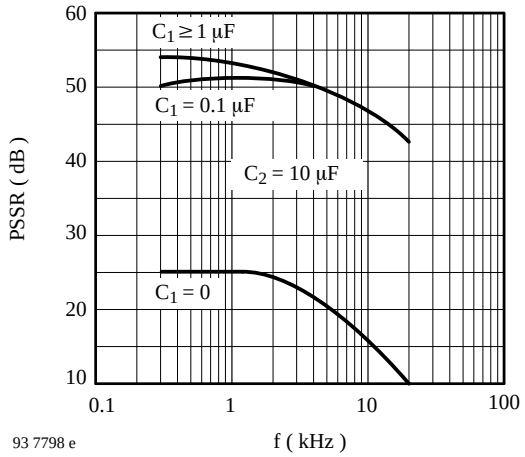

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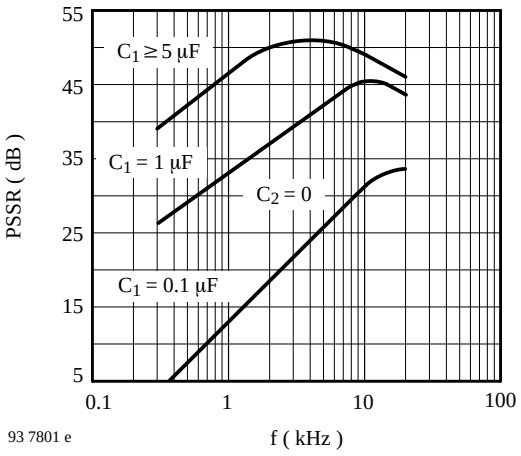

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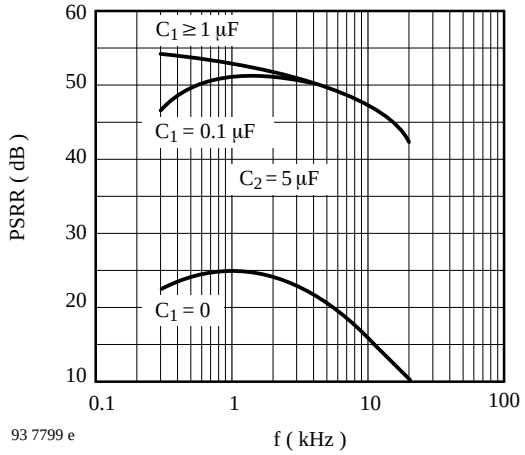

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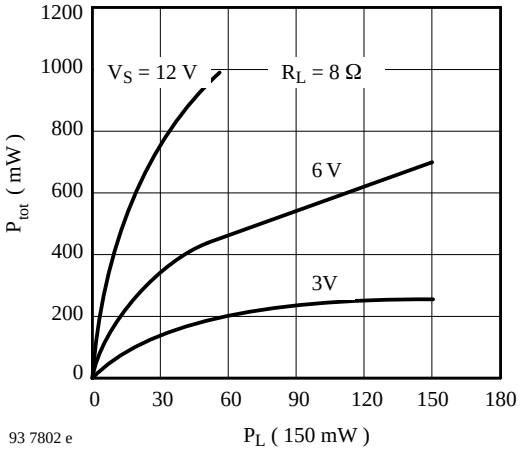

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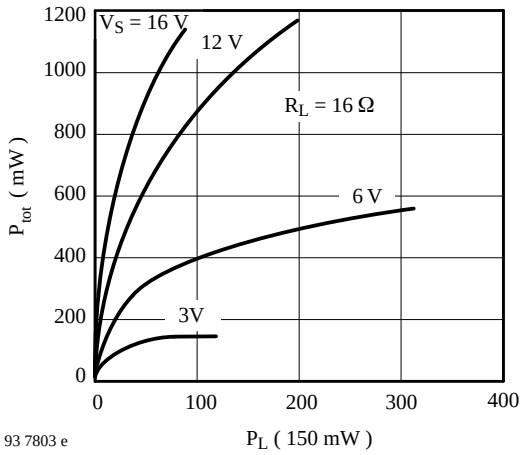

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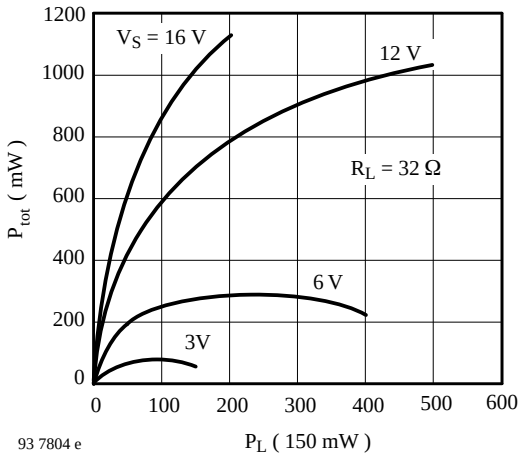

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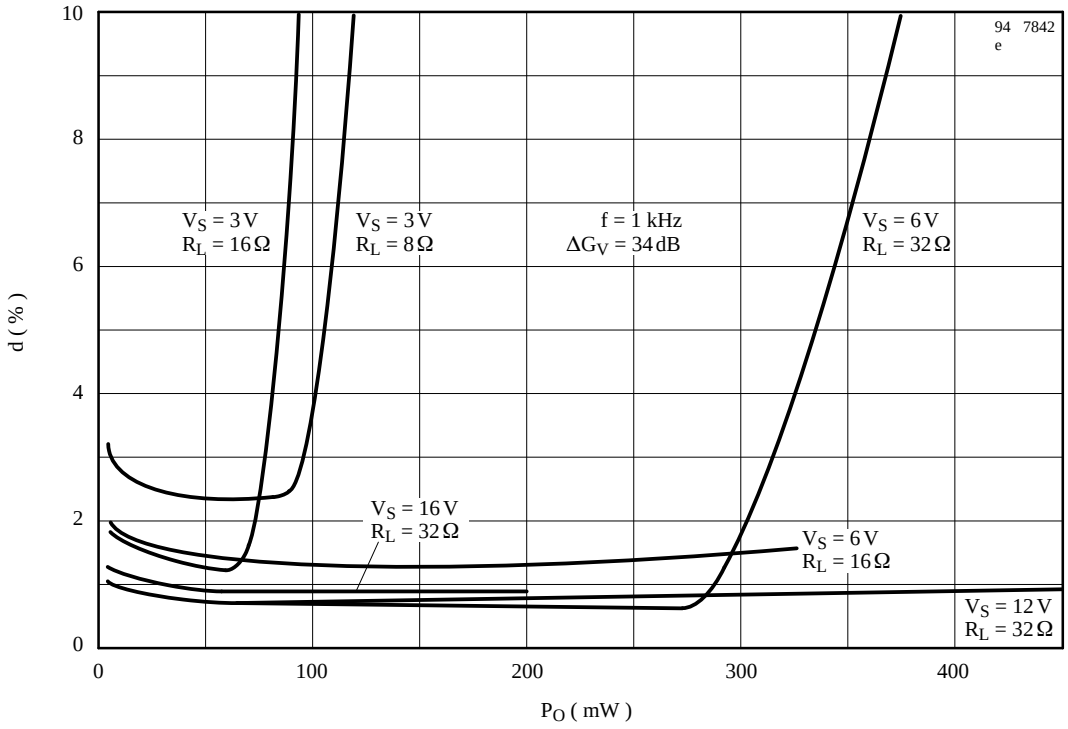

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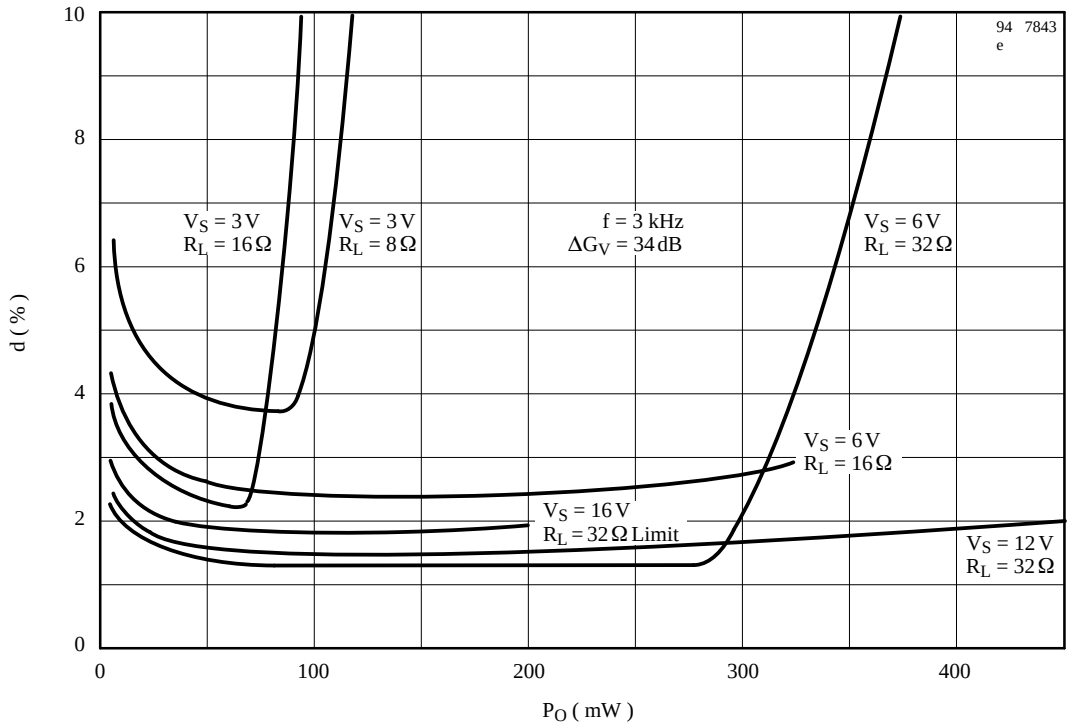

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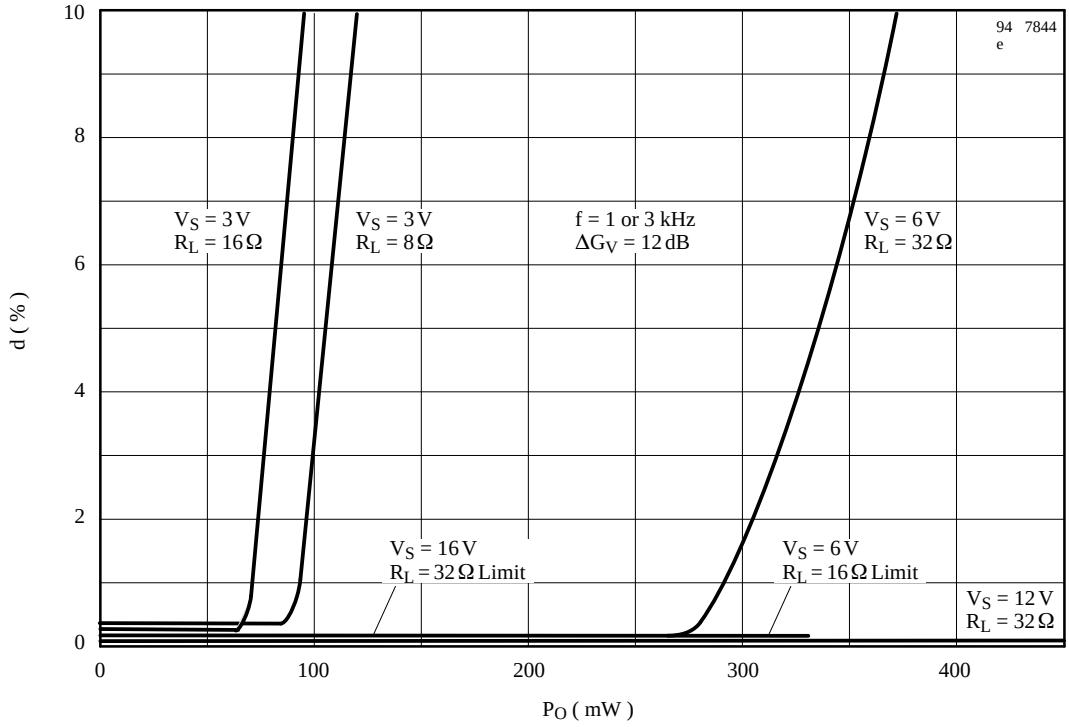

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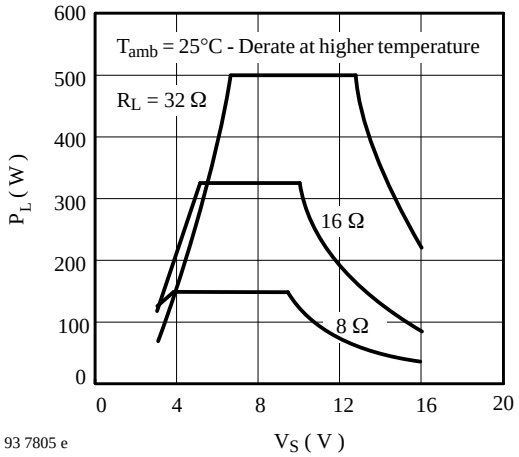

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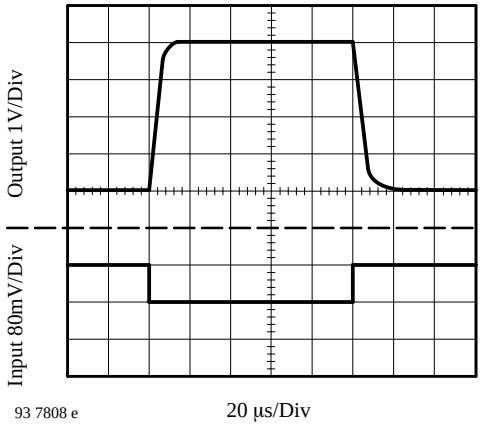

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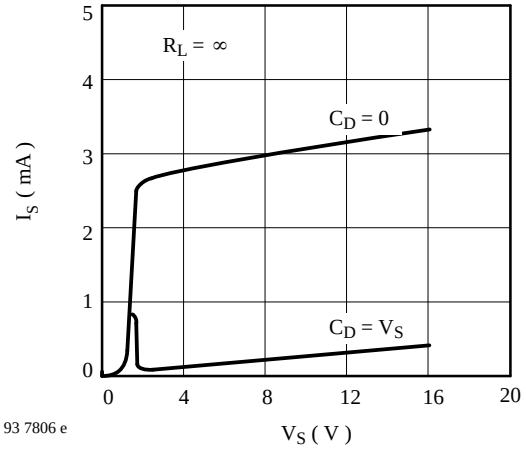

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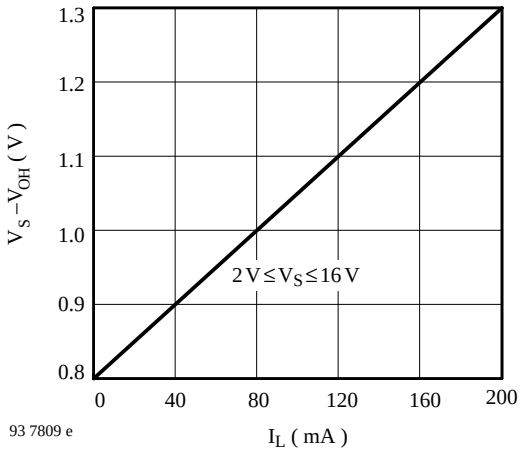

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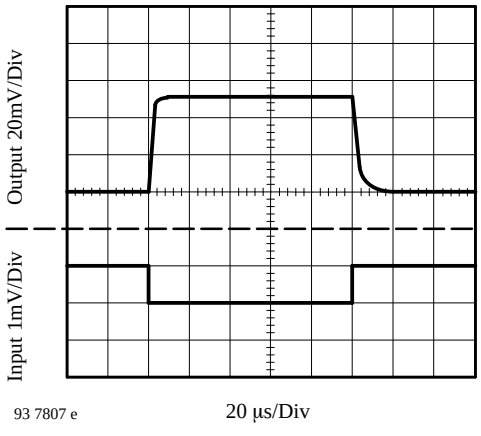


Figure 16.

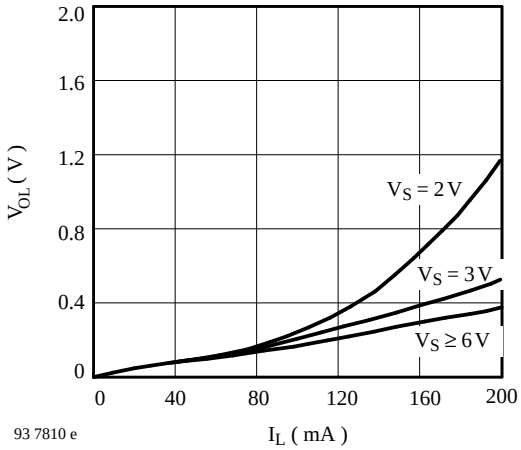
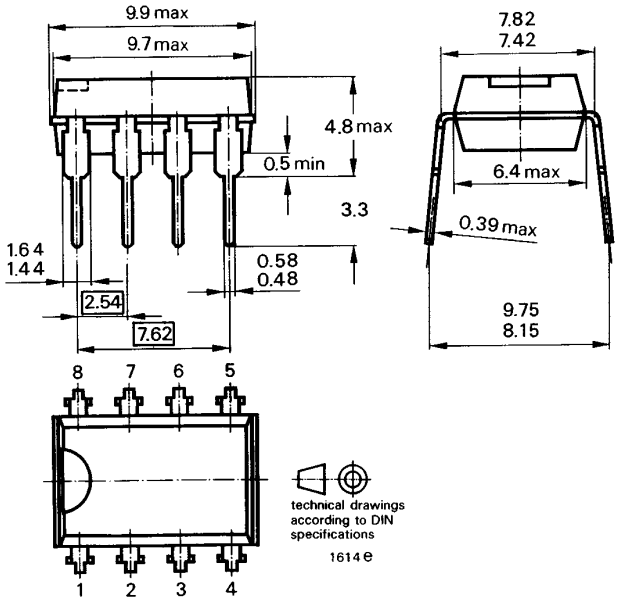


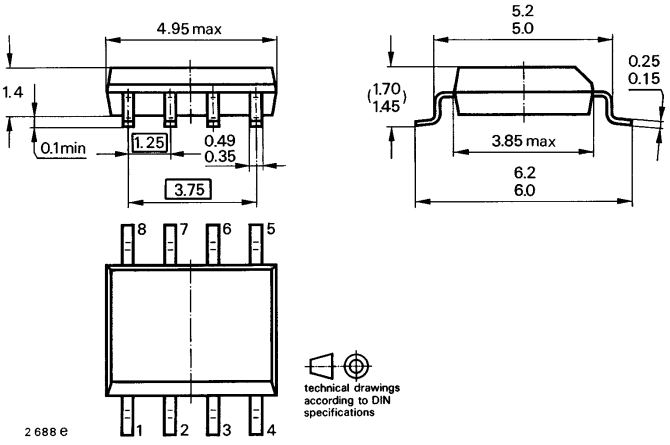
Figure 19.

Dimensions in mm

Package: DIP 8



Package: SO 8



Ozone Depleting Substances Policy Statement

It is the policy of **TEMIC TELEFUNKEN microelectronic GmbH** to

1. Meet all present and future national and international statutory requirements.

2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

TEMIC TELEFUNKEN microelectronic GmbH semiconductor division has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively

2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA

3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

TEMIC can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

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